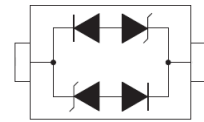


Features

- 350 Watts peak pulse power ($t_p = 8/20\mu s$)
- Low clamping voltage
- Working voltage: $V_{RWM} = 3V, 5V, 8V, 12V, 15V, 24V, 36V$
- Low reverse clamping voltage

HF



Typical Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Portable instrumentation



Mechanical Data

- Case: SOD-123
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

SOD-123

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
DLC03CW	SOD-123	3000pcs / Tape & Reel	03C
DLC05CW	SOD-123	3000pcs / Tape & Reel	C05C
DLC08CW	SOD-123	3000pcs / Tape & Reel	8C
DLC12CW	SOD-123	3000pcs / Tape & Reel	2C
DLC15CW	SOD-123	3000pcs / Tape & Reel	6C
DLC24CW	SOD-123	3000pcs / Tape & Reel	4C
DLC36CW	SOD-123	3000pcs / Tape & Reel	36C

Maximum Ratings (@ $T_A = 25^\circ C$ unless otherwise specified)

Parameter	Symbol	Value	Unit
IEC 61000-4-2; ESD (Air)	V_{ESD-A}	± 30	kV
IEC 61000-4-2; ESD (Contact)	V_{ESD-C}	± 30	kV
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	350	W

Thermal Characteristics

Parameter	Symbol	Value	Unit
Junction Temperature	T_J	125	$^\circ C$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ C$

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
DLC03CW TVS for 3V Lines						
Reverse Stand-off Voltage	V_{RWM}		-	-	3	V
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1\text{mA}$	4	-	-	V
Reverse Leakage Current	I_R	$V_{RWM} = 3\text{V}$	-	-	5	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	7	V
		$I_{PP} = 20\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	19	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$	-	1	-	pF
DLC05CW TVS for 5V Lines						
Reverse Stand-off Voltage	V_{RWM}		-	-	5	V
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1\text{mA}$	6	-	-	V
Reverse Leakage Current	I_R	$V_{RWM} = 5\text{V}$	-	-	5	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	9.8	V
		$I_{PP} = 20\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	20	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$	-	1	-	pF
DLC08CW TVS for 8V Lines						
Reverse Stand-off Voltage	V_{RWM}		-	-	8	V
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1\text{mA}$	8.5	-	-	V
Reverse Leakage Current	I_R	$V_{RWM} = 8\text{V}$	-	-	2	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	13.4	V
		$I_{PP} = 17\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	18.5	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$	-	1	-	pF
DLC12CW TVS for 12V Lines						
Reverse Stand-off Voltage	V_{RWM}		-	-	12	V
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1\text{mA}$	13.3	-	-	V
Reverse Leakage Current	I_R	$V_{RWM} = 12\text{V}$	-	-	1	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	19	V
		$I_{PP} = 11\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	28.6	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$	-	1	-	pF
DLC15CW TVS for 15V Lines						
Reverse Stand-off Voltage	V_{RWM}		-	-	15	V
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1\text{mA}$	16.7	-	-	V
Reverse Leakage Current	I_R	$V_{RWM} = 15\text{V}$	-	-	1	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	24	V
		$I_{PP} = 10\text{A}$, $t_p = 8/20\mu\text{s}$	-	-	31.8	V

Junction Capacitance	C_J	$V_R = 0V, f = 1MHz$	-	1	-	pF
DLC24CW TVS for 24V Lines						
Reverse Stand-off Voltage	V_{RWM}		-	-	24	V
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1mA$	26.7	-	-	V
Reverse Leakage Current	I_R	$V_{RWM} = 24V$	-	-	1	μA
Clamping Voltage	V_C	$I_{PP} = 1A, t_p = 8/20\mu s$	-	-	43	V
		$I_{PP} = 6A, t_p = 8/20\mu s$	-	-	56	V
Junction Capacitance	C_J	$V_R = 0V, f = 1MHz$	-	1	-	pF
DLC36CW TVS for 36V Lines						
Reverse Stand-off Voltage	V_{RWM}		-	-	36	V
Reverse Breakdown Voltage	$V_{(BR)}$	$I_T = 1mA$	40	-	-	V
Reverse Leakage Current	I_R	$V_{RWM} = 36V$	-	-	1	μA
Clamping Voltage	V_C	$I_{PP} = 1A, t_p = 8/20\mu s$	-	-	48	V
		$I_{PP} = 4A, t_p = 8/20\mu s$	-	-	90	V
Junction Capacitance	C_J	$V_R = 0V, f = 1MHz$	-	1.5	-	pF

Ratings and Characteristic Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

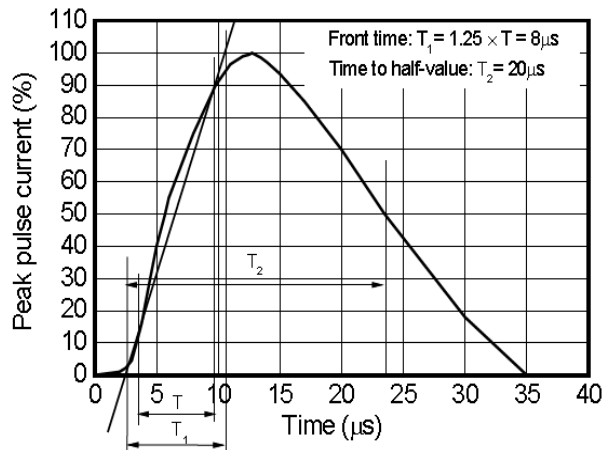


Fig 1 8/20 μs waveform per IEC61000-4-5

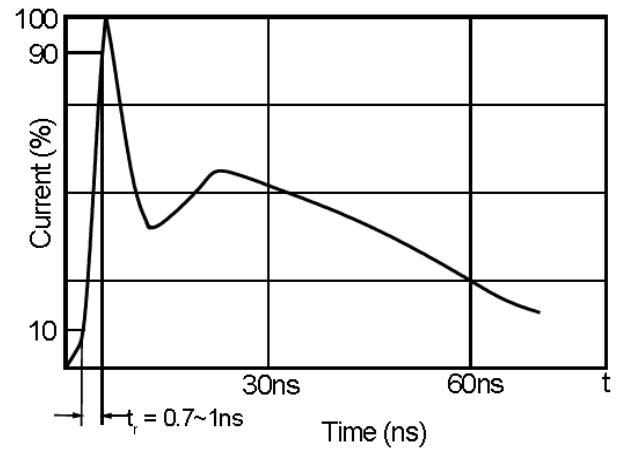


Fig 2 ESD pulse waveform according to IEC61000-4-2

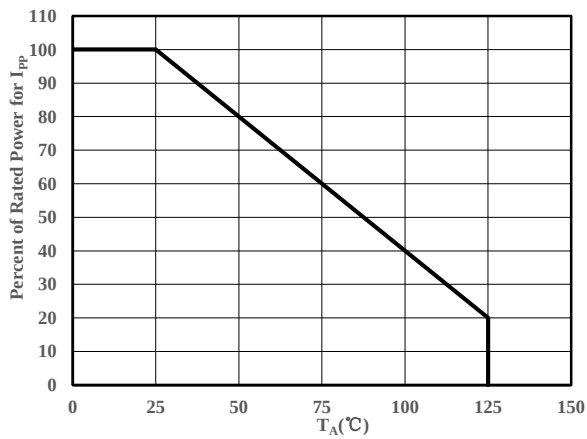
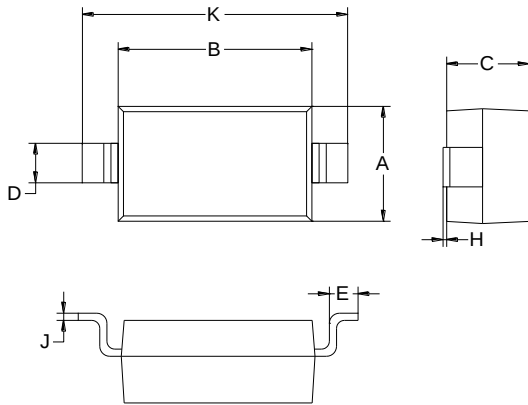


Fig 3 Power Derating Curve

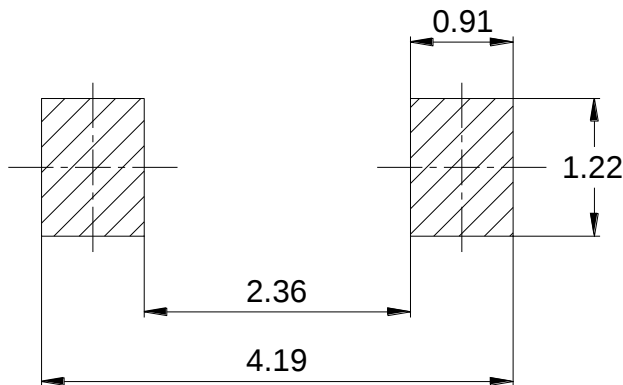
Package Outline Dimensions (Unit: mm)



SOD-123		
Dimension	Min.	Max.
A	1.45	1.75
B	2.55	2.85
C	1.00	1.30
D	0.50	0.60
E	0.25	0.45
H	0.02	0.10
J	0.05	0.15
K	3.55	3.85

Package Outline Dimensions (Unit: mm)

SOD-123



IMPORTANT NOTICE

Changzhou Galaxy Century Microelectronics (GME) reserves the right to make changes without further notice to any product information (copyrighted) herein to make corrections, modifications, improvements, or other changes. GME does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others.